

# PUMX1

# 40 V, 100 mA NPN/NPN general-purpose transistor Rev. 04 — 20 January 2010 Produ

**Product data sheet** 

#### 1. **Product profile**

### 1.1 General description

NPN/NPN general-purpose transistor with two independently operating transistors in a SOT363 (SC-88) very small Surface-Mounted Device (SMD) plastic package.

Table 1. **Product overview** 

| Type number |        |       | PNP/PNP    | NPN/PNP    |  |
|-------------|--------|-------|------------|------------|--|
|             | NXP    | JEITA | complement | complement |  |
| PUMX1       | SOT363 | SC-88 | PUMT1      | PUMZ1      |  |

### 1.2 Features

- Double general-purpose transistor
- Board-space reduction
- Very small SMD plastic package

### 1.3 Applications

General-purpose switching and amplification

#### **Pinning information** 2.

Table 2 Dinning

| Table 2. | Finning       |                    |                |
|----------|---------------|--------------------|----------------|
| Pin      | Description   | Simplified outline | Graphic symbol |
| 1        | emitter TR1   |                    |                |
| 2        | base TR1      | 654                | 6 5 4          |
| 3        | collector TR2 |                    | TR2            |
| 4        | emitter TR2   | 0                  | (TR1)          |
| 5        | base TR2      | □1 □2 □3           |                |
| 6        | collector TR1 |                    | 1 2 3          |
|          |               |                    | sym020         |
|          |               |                    |                |



### 40 V, 100 mA NPN general-purpose double transistor

# 3. Ordering information

Table 3. Ordering information

| Type number | Package |  |         |  |  |
|-------------|---------|--|---------|--|--|
|             | Name    | Description                              | Version |  |  |
| PUMX1       | SC-88   | plastic surface-mounted package; 6 leads | SOT363  |  |  |

# 4. Marking

Table 4. Marking codes

| Type number | Marking code[1] |
|-------------|-----------------|
| PUMX1       | <b>Z*Z</b>      |

<sup>[1] \* = -:</sup> made in Hong Kong

# 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter                 | Conditions                  | Min          | Max  | Unit |  |
|------------------|---------------------------|-----------------------------|--------------|------|------|--|
| Per transistor   |                           |                             |              |      |      |  |
| $V_{CBO}$        | collector-base voltage    | open emitter                | -            | 50   | V    |  |
| $V_{CEO}$        | collector-emitter voltage | open base                   | -            | 40   | V    |  |
| $V_{EBO}$        | emitter-base voltage      | open collector              | -            | 5    | V    |  |
| I <sub>C</sub>   | collector current         |                             | -            | 100  | mA   |  |
| I <sub>CM</sub>  | peak collector current    |                             | -            | 200  | mA   |  |
| I <sub>BM</sub>  | peak base current         |                             | -            | 200  | mA   |  |
| P <sub>tot</sub> | total power dissipation   | $T_{amb} \le 25  ^{\circ}C$ | -            | 200  | mW   |  |
| Per device       | )                         |                             |              |      |      |  |
| P <sub>tot</sub> | total power dissipation   | $T_{amb} \le 25  ^{\circ}C$ | <u>[1]</u> - | 300  | mW   |  |
| T <sub>j</sub>   | junction temperature      |                             | -            | 150  | °C   |  |
| T <sub>amb</sub> | ambient temperature       |                             | -65          | +150 | °C   |  |
| T <sub>stg</sub> | storage temperature       |                             | -65          | +150 | °C   |  |

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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<sup>\* =</sup> p: made in Hong Kong

<sup>\* =</sup> t: made in Malaysia

<sup>\* =</sup> W: made in China

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### 40 V, 100 mA NPN general-purpose double transistor

### 6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol        | Parameter                                   | Conditions  | Min   | Тур | Max | Unit |
|---------------|---|-------------|-------|-----|-----|------|
| Per device    |   |             |       |     |     |      |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | [1] - | -   | 416 | K/W  |

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

### 7. Characteristics

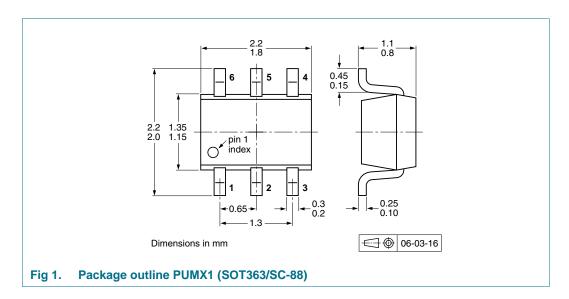
Table 7. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

| · arrib = 0      | o amoso carormos opcomosar           |  |              |     |     |      |
|------------------|--------------------------------------|--|--------------|-----|-----|------|
| Symbol           | Parameter                            | Conditions   | Min          | Тур | Max | Unit |
| Per transi       | stor                                 |  |              |     |     |      |
| I <sub>CBO</sub> | collector-base cut-off current       | $V_{CB} = 30 \text{ V};$ $I_{E} = 0 \text{ A}$                           | -            | -   | 100 | nA   |
|                  |                                      | $V_{CB} = 30 \text{ V};$ $I_{E} = 0 \text{ A};$ $T_{j} = 150 \text{ °C}$ | -            | -   | 10  | μА   |
| I <sub>EBO</sub> | emitter-base cut-off current         | $V_{EB} = 4 V;$ $I_C = 0 A$  | -            | -   | 100 | nA   |
| h <sub>FE</sub>  | DC current gain                      | $V_{CE} = 6 V;$ $I_{C} = 1 \text{ mA}$                                   | 120          | -   | -   |      |
| $V_{CEsat}$      | collector-emitter saturation voltage | $I_C = 50 \text{ mA};$<br>$I_B = 5 \text{ mA}$                           | <u>[1]</u> _ | -   | 200 | mV   |
| f <sub>T</sub>   | transition frequency                 | $I_C = 2 \text{ mA};$<br>$V_{CE} = 12 \text{ V};$<br>f = 100  MHz        | 100          | -   | -   | MHz  |
| C <sub>c</sub>   | collector capacitance                | $V_{CB} = 12 \text{ V};$ $I_E = i_e = 0 \text{ A};$ $f = 1 \text{ MHz}$  | -            | -   | 1.5 | pF   |
|                  |                                      |  |              |     |     |      |

<sup>[1]</sup> Pulse test:  $t_p \leq 300~\mu s;~\delta \leq 0.02.$ 

# 8. Package outline



# 9. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Туре         | Package                            | Description                        |      | Packing quantity |       |
|--------------|------------------------------------|------------------------------------|------|------------------|-------|
| number       |                                    |                                    |      | 3000             | 10000 |
| PUMX1 SOT363 | 4 mm pitch, 8 mm tape and reel; T1 | [2]                                | -115 | -135             |       |
|              |                                    | 4 mm pitch, 8 mm tape and reel; T2 | [3]  | -125             | -165  |

<sup>[1]</sup> For further information and the availability of packing methods, see Section 12.

[2] T1: normal taping

[3] T2: reverse taping



# 40 V, 100 mA NPN general-purpose double transistor

# 10. Revision history

### Table 9. Revision history

| Document ID    | Release date  | Data sheet status                  | Change notice       | Supersedes |  |  |
|----------------|---|------------------------------------|---------------------|------------|--|--|
| PUMX1_4        | 20100120  | Product data sheet                 | -                   | PUMX1_3    |  |  |
| Modifications: | <ul> <li>The format of this data sheet has been redesigned to comply with the new identity<br/>guidelines of NXP Semiconductors.</li> </ul> |                                    |                     |            |  |  |
|                | <ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>  |                                    |                     |            |  |  |
|                | <ul> <li><u>Table 1 "Product overview"</u>: added</li> </ul>  |                                    |                     |            |  |  |
|                | Section 1.2 "Features": updated   |                                    |                     |            |  |  |
|                | <ul> <li>Section 1.3 "</li> </ul>   | Applications": amended             |                     |            |  |  |
|                | Section 2 "Pi   | inning information": amended       |                     |            |  |  |
|                | • Figure 1: sup   | perseded by minimized packa        | age outline drawing |            |  |  |
|                | Section 9 "Page 1.5"  | acking information": added         |                     |            |  |  |
|                | Section 11 "L   | <u>egal information"</u> : updated |                     |            |  |  |
| PUMX1_3        | 19990414  | Preliminary specification          | -                   | PUMX1_2    |  |  |
| PUMX1_2        | 19970709  | Preliminary specification          | -                   | PUMX1_1    |  |  |
|                |   |                                    |                     |            |  |  |

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### 11. Legal information

### 11.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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For sales office addresses, please send an email to: <a href="mailto:salesaddresses@nxp.com">salesaddresses@nxp.com</a>

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